

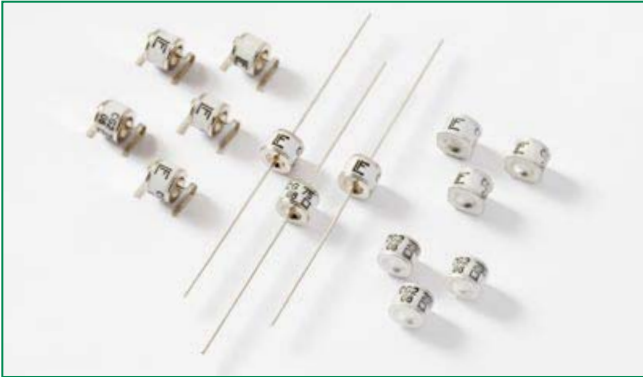


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CG/CG2 Series



Agency Approvals

AGENCY	AGENCY FILE NUMBER
	E128662
	E320116

2 Electrode GDT Graphical Symbol



Description

Littelfuse highly reliable CG/CG2 Series GDTs provide a high degree of surge protection in a small size ideal for board level circuit protection.

GDTs function as switches which dissipate a minimum amount of energy and therefore handle currents that far surpass other types of transient voltage protection. Their gas-filled, rugged ceramic metal construction make them well suited to adverse environments.

The CG/CG2 series comes in a variety of forms including surface mount, core, straight and shaped leads, to serve a variety of mounting methods.

The CG Series (75-110V) is ideal for protection of test and communication equipment and other devices in which low voltage limits and extremely low arc voltages are required.

The CG2 Series (145V-1000V) is ideal for protecting equipment where higher voltage limits and holdover voltages are necessary.

NOTE REGARDING 'SN' PRODUCTS: CG2 SN products were designed for surge protection applications for which the radioactive isotope used in standard CG/CG2 devices is not desired. Since the end of 2007 all CG/CG2 products are non-radioactive. See Part Numbering System diagram for additional ordering information.

Features

- Rugged Ceramic-Metal construction
- Low Capacitance (<1.5pf)
- Meets REA PE-80
- Available in surface mount, and a variety of lead options

Applications

- Communication lines and equipment
- CATV equipment
- Test equipment
- Data lines
- Power supplies
- Instrumentation circuits
- Medical electronics
- ADSL equipment
- Telecom SLIC protection

Electrical Characteristics

Part Number	Device Specifications (at 25°C)							Life Ratings																		
	DC Breakdown in Volts (@100V/s)			Impulse Break-down in Volts (@100V/μs)	Impulse Break-down In Volts (@1 Kv/μsec)	Insulation Resistance	Capacitance (@1MHz)	Arc Voltage (on state Voltage) @1Amp Min	Surge Life (@500A 10/1000μs)	Nominal Impulse Discharge Current (8/20μs)	Nominal AC Discharge Current (10x1sec @50-60Hz)	AC Dischage Current (9 cycle @50Hz)	DC Holdover Voltage ²	Max Impulse Discharge Current (1 Application @ 10/350μs)												
	MIN	TYP	MAX	MAX		MIN	MAX	TYP					TYP													
CG75	60	75	90	400	650	10 ¹⁰ Ω (at 50V)	1.5 pF	15 V	400 shots	10 shots (@20kA) ³	20 A	100 A	52 V	4kA												
CG90	72	90	108	400	600								80 V	2.5kA												
CG90 SN	72	90	108	400	600										135 V											
CG110	88	110	132	450	600																					
CG2145	116	145	174	500	600																					
CG2145 SN	120	145	174	500	600																					
CG2230	195	230	265	600	700																					
CG2230 SN	184	230	276	600	700																					
CG2250	213	250	288	625	725																					
CG2250 SN	200	250	300	625	725																					
CG2300	255	300	345	700	800																					
CG2300 SN	240	300	360	700	800																					
CG2350	297	350	403	750	900																					
CG2350 SN	280	350	420	750	900																					
CG2420	357	420	483	800	1000																					
CG2470	400	470	540	850	1200																					
CG2470 SN	376	470	564	850	1200																					
CG2600	510	600	690	1000	1400																					
CG2600 SN	480	600	720	1000	1400																					
CG2800 ¹	680	800	920	1200	1500																					
CG21000 ¹	850	1000	1150	1500	1600	10 shots (@10kA)	10 A	65 A																		

NOTES:

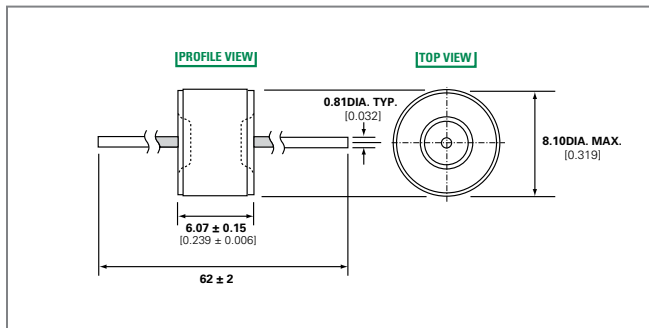
- Tested to UL1449 Third Edition
- Reference REA PE-80, 0.2A. Tested to ITU-T Rec K.12 and REA PE 80 < 150 mSec.
- Leaded devices = 5x[5(+)] or 5 (-)] applications 20kA 8/20μSec. (75 to 600 volt devices.)
 MS and Core devices = 10x[5(+)] and 5(-)] applications 10kA 8/20μS (800 to 1000 volt devices.)

Product Characteristics

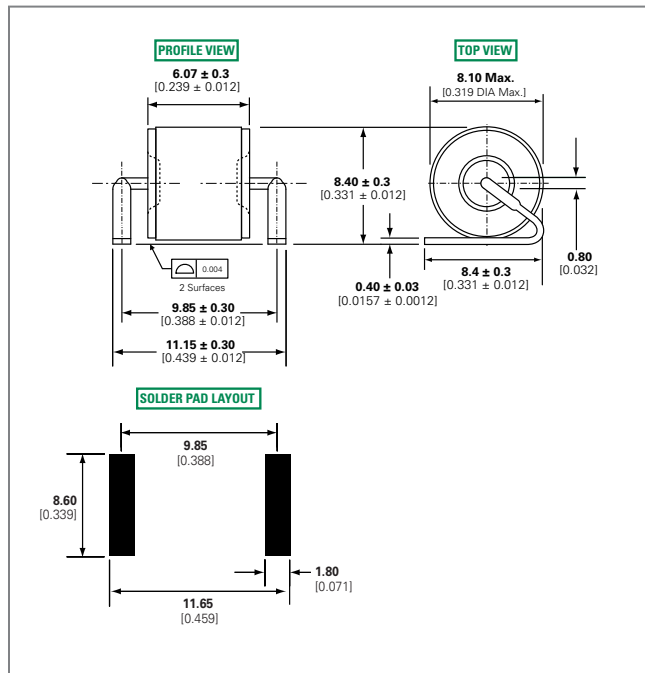
Materials	LS, Axial: Device: Nickel Plated 2–5 Microns Lead Wires: Tin Plated 17.5 ± 12.5 Microns Construction: Ceramic Insulator Core: Device: Tin Plated 17.5 ± 12.5 Microns. Construction: Ceramic Insulator MS: Device: Dull Tin Plated 7–9 Microns Construction: Ceramic Insulator	Glow to arc transition current < 0.5Amps
		Glow Voltage 60-160 Volts
Product Marking	LF Logo, Voltage and date code; Black in positive print	Storage and Operational Temperature -40 to +90
		Maximum Follow On Current¹ 230 Volts r.m.s, 200 Amps. (800V and 1000V devices tested to UL1449 3rd edition)

Device Dimensions

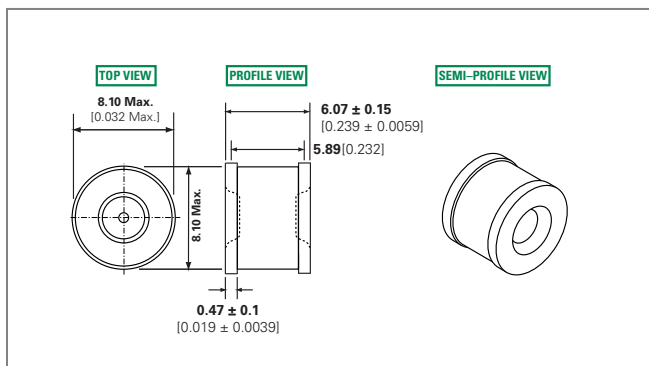
Leaded 'L' Type Straight Axial Devices



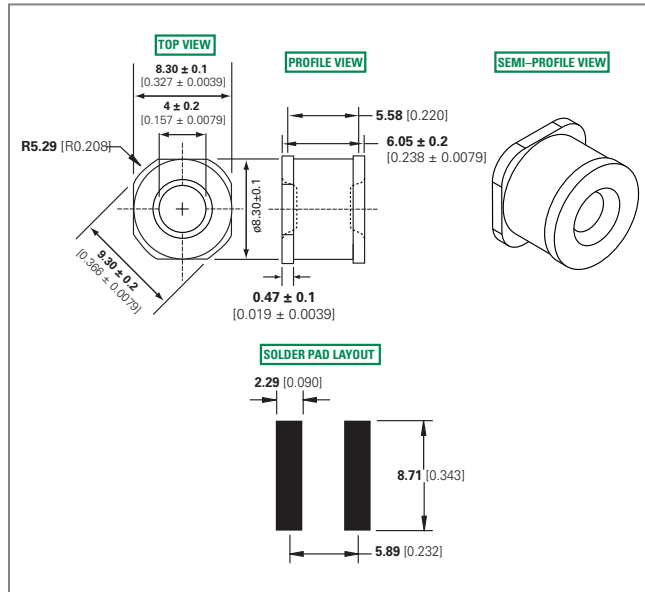
Leaded 'LS' Type Shaped Lead Devices



Core Devices

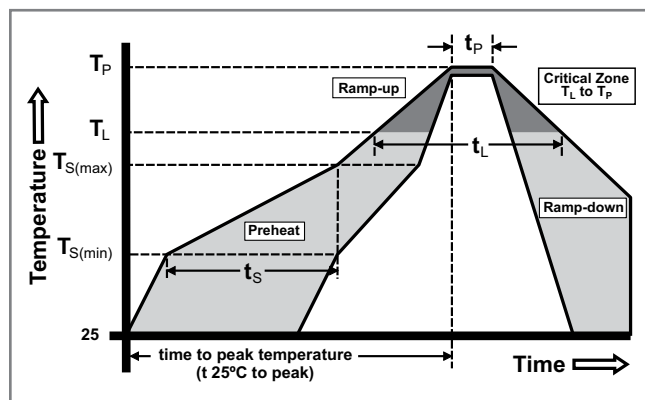


'MS' Type Devices

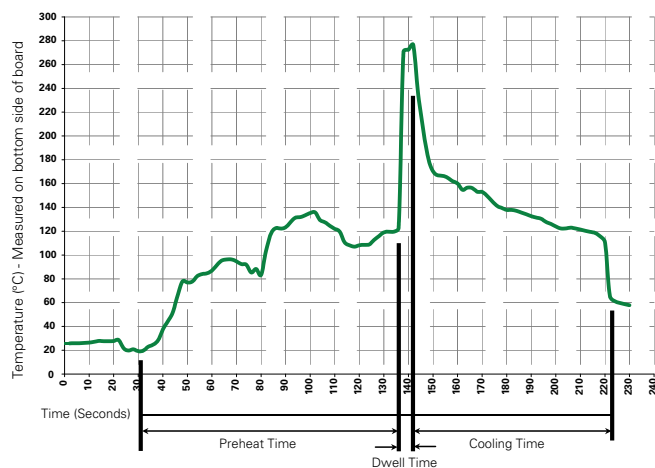


Soldering Parameters - Reflow Soldering (Surface Mount Devices)

Reflow Condition		Pb – Free assembly
Pre Heat	- Temperature Min ($T_{s(min)}$)	150°C
	- Temperature Max ($T_{s(max)}$)	200°C
	- Time (Min to Max) (t_s)	60 – 180 secs
Average ramp up rate (Liquidus Temp (T_L) to peak)		3°C/second max
$T_{s(max)}$ to T_L - Ramp-up Rate		5°C/second max
Reflow	- Temperature (T_L) (Liquidus)	217°C
	- Temperature (t_L)	60 – 150 seconds
Peak Temperature (T_p)		260 ^{+0/-5} °C
Time within 5°C of actual peak Temperature (t_p)		10 – 30 seconds
Ramp-down Rate		6°C/second max
Time 25°C to peak Temperature (T_p)		8 minutes Max.
Do not exceed		260°C



Soldering Parameters - Wave Soldering (Thru-Hole Devices)



Recommended Process Parameters:

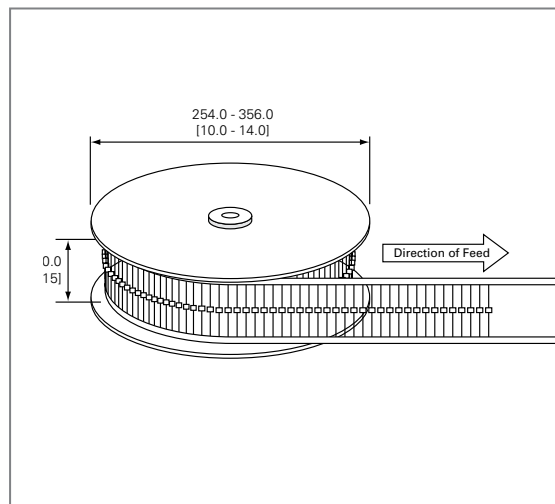
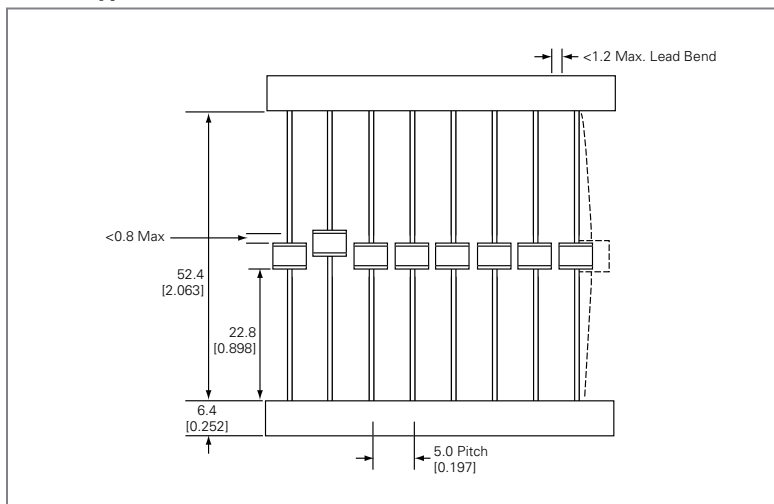
Wave Parameter	Lead-Free Recommendation
Preheat:	
(Depends on Flux Activation Temperature)	(Typical Industry Recommendation)
Temperature Minimum:	100° C
Temperature Maximum:	150° C
Preheat Time:	60-180 seconds
Solder Pot Temperature:	280° C Maximum
Solder Dwell Time:	2-5 seconds

Soldering Parameters - Hand Soldering

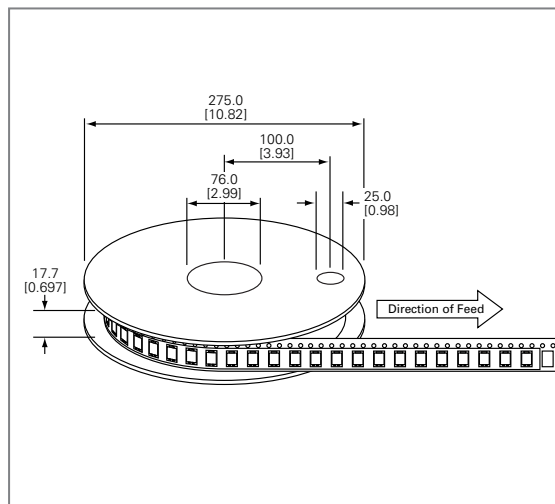
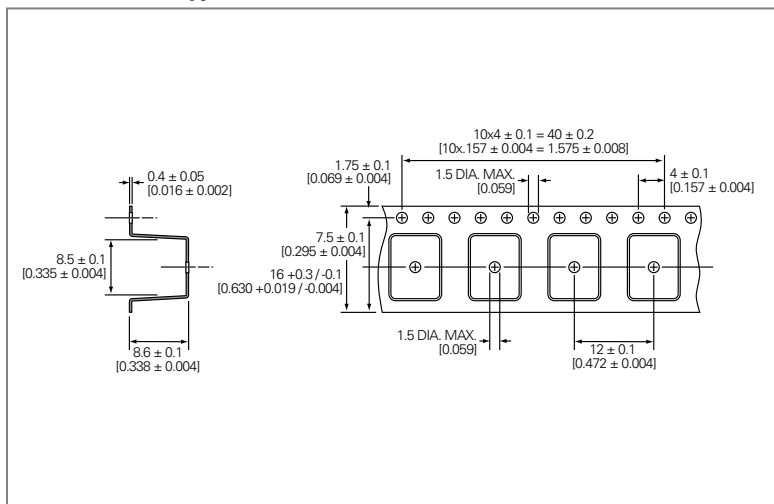
Solder Iron Temperature: 350° C +/- 5°C
Heating Time: 5 seconds max.

Packaging Dimensions

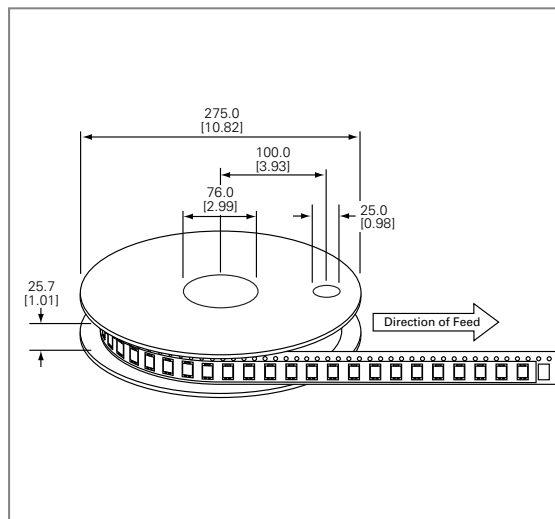
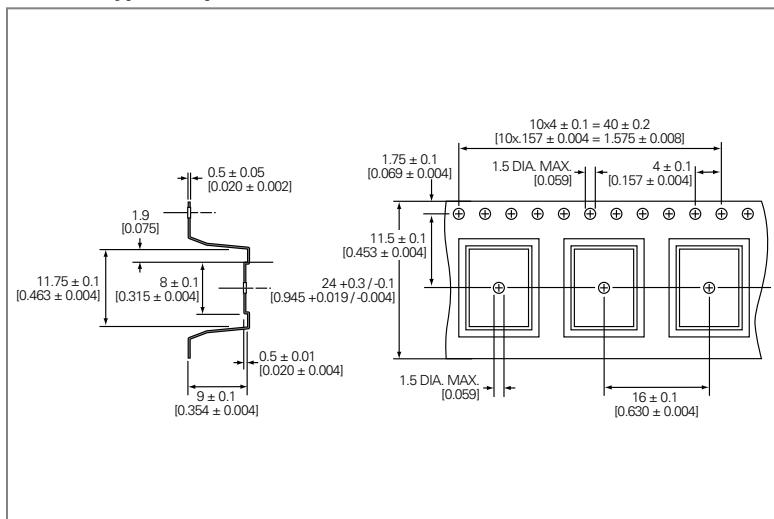
For 'L' Type Axial Lead Items



Core and 'MS' Type Items



For 'LS' Type Shaped Lead Items



Part Numbering System and Ordering Information

CG2 XXX XX * XX

Series

CG – for 75, 90, or 110V
CG2 – for 145V to 1000V

Breakdown Voltage

75	300
90	350
110	470
145	600
230	800
250	1000

Lead Option Code

(Blank) = No Leads / Core
L = Straight Leads
LS = Shaped Leads
MS = Surface Mount

Option Code*

SN = denotes different DC Breakover Voltage Limit. Please refer to Electrical Characteristics table for additional information.

Packaging Option Code

(Blank) = No Leads / Core, Bulk Bag - 400 pcs
L(Blank) = Straight Lead, Tray - 50 pcs
LTR = Straight Lead, Tape & Reel per EIA RS-296-E - 500 per reel
LTE = Straight Lead, Tape & Reel per IEC 60286-1 - 500 per reel
LSTR = Shaped Lead (see LS dimensions), Tape & Reel - 500 per reel

Examples:

CG75 – A non-leaded 75V device
CG2230L – A leaded 230V device
CG2800LTR – A leaded 800V device, tape-and-reel (per EIA standard RS-296-D)

Notes:

CG/CG2 devices with other breakdown voltages in the 75-1000 V range are available upon request.